# 2SA2009

## Silicon PNP epitaxial planar type

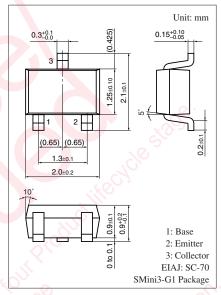
For low-frequency high breakdown voltage amplification

### ■ Features

- High collector-emitter voltage (Base open) V<sub>CEO</sub>
- Low noise voltage NV
- S-Mini type package, allowing downsizing and thinning of the equipment and automatic insertion through the tape packing.

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	-120	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	-120	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	-5	V	
Collector current	$I_{C}$	-20	mA	
Peak collector current	$I_{CP}$	-50	mA	
Collector power dissipation	P <sub>C</sub>	150	mW	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	



Marking Symbol: AR

## ■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = -10 \; \mu A, \; I_{\rm E} = 0$	-120	25		V
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_{\rm C} = -1  \text{mA},  I_{\rm B} = 0$	-120			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_{\rm E} = -10 \; \mu \text{A}, \; I_{\rm C} = 0$	-5			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -50 \text{ V}, I_E = 0$			-100	nA
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = -50 \text{ V}, I_B = 0$			-1	μΑ
Forward current transfer ratio *	$h_{FE}$	$V_{CE} = -5 \text{ V}, I_C = -2 \text{ mA}$	180		700	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -20 \text{ mA}, I_B = -2 \text{ mA}$			- 0.6	V
Transition frequency	$f_T$	$V_{CB} = -5 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Noise voltage	NV	$V_{CE} = -40 \text{ V}, I_C = -1 \text{ mA}, G_V = 80 \text{ dB}$			130	mV
M.		$R_g = 100 \text{ k}\Omega$ , Function = FLAT				

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

#### 2. \*: Rank classification

Rank	R	S	Т
h <sub>FE</sub>	180 to 360	260 to 520	360 to 700

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